



FIXED VOLTAGE REGULATOR (POSITIVE)

LM78L05

3-TERMINAL 0.1A POSITIVE VOLTAGE REGULATORS

This series of fixed-voltage monolithic integrated-circuit voltage regulators is designed for a wide range of applications.

These applications include on-card regulation for elimination of noise and distribution problems associated with single-point regulation.

In addition, they can be used with power-pass elements to make high current voltage regulators.

Each of these regulators can deliver up to 100mA output current.

The internal limiting and thermal shutdown features of these regulators make them essentially immune to overload. When used as a replacement for a zener diode-resistor combination, an effective improvement in output impedance can be obtained together with lower-bias current.



FEATURES

 \diamondsuit Output current up to 100mA

- ♦ No External Components
- \diamondsuit Internal Thermal Overload Protection
- ♦ Internal Short-Circuit Limiting
- \diamondsuit Output Voltage of 5V, 6V, 8V, 9V, 10V, 12V, 15V, 18V

and 24V

ABSOLUTE MAXIMUM RATINGS

Characteristic		Symbol	Value	Unit	
Input Voltage	LM78L05 ~ LM78L10	VI	30	V	
	LM78L12 ~ LM78L18	v1	35		
Operating Junction Temperature		Topr	0 ~ +150		
Storage Temperature		Tstg	-65 ~ +150	°C	
Soldering Temperature and Time		Tsol	260/10sec		





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RECOMMENDED OPERATING CONDITIONS

Characteristic		Min .	Max.	Unit	
	LM78L05	7	20		
	LM78L06	8	20		
	LM78L08	10.5	23		
	LM78L09	11.5	24		
Input Voltage, VI	LM78L10	12.5	25	v	
	LM78L12	14.5	27		
	LM78L15	17.5	30		
	LM78L18	20.5	33		
	LM78L24	26.5	39		
Output Current, Io			100	mA	
Operating Virtual Junction Temperature, Tj		0	125	°C	

TYPICAL APPLICATION



Note s

- 1. To specify an output voltage, substitute voltage for "XX"
- 2. Bypass capacitors are recommended for optimum stability and transient response and should be located as close as possible to the regulators.







MADE IN KOREA

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LM78L05 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, VI=10V, Io=40mA (unless otherwise noted)

Characteristic	Symbol	Test Condition *		Min.	Тур.	Ma x.	Unit
Output Voltage **	Vout	25°C		4.8	5	5.2	
		1mA≤lo≤40mA 7V≤VI≤Vmax	0°C ~ 125°C	4.75	5	5.25	v
		1mA≼ lo≤ 70mA		4.75	5	5.25	
Line Regulation	Reg line	7V≼ VI≤20V	250		32	150	mV
		8V≤VI≤20V	25°C		26	100	
Load Regulation	Reg load	1mA≤b≤100mA	25°C		15	60	mV
		1mA≤lo≤40mA	250		8	30	
Bias Current	lB		25°C		3.8	6	mΛ
			125°C			5.5	mA
Bias Current Change	ΔІв	9V≤ VI≤20V	0°C ~ 125°C			1.5	mA
		1mA≤lo≤40mA	00 ~ 1250			0.1	
Output Noise Voltage	VN	10Hz ≤f≤100kHz	25°C		42		μV
Ripple Rejection	RR	8V≼VI≤18V f=120Hz	25°C	41	49		dB
Dropout Voltage	VD		25°C		1.7		V

Notes

*. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a 0.33μ F capacitor across the input and a 0.1μ F capacitor across the output.

**. This specification applies only for DC power dissipation permitted by absolute maximum ratings.